

SAM™ Data Sheet SAM-1040-2-1ps-x, λ = 1040 nm

Laser wavelength		$\lambda = 1040 \text{ nm}$
High reflection band		λ = 1010 1070 nm
Absorbance		A ₀ = 2 %
Modulation depth		∆R = 1.2 %
Non-saturable loss		A _{ns} = 0.8 %
Saturation fluence		Φ_{sat} = 60 µJ/cm ²
Relaxation time constant		τ ~ 1 ps
Damage threshold		$\Phi = 4 \text{ mJ/cm}^2$
Chip area		4.0 mm x 4.0 mm; other dimensions on request
Chip thickness		450 μm
Protection		the SAM is protected with a dielectric front layer
x = x =	0 12.7 g	type of mounting as follows: unmounted glued on a gold plated Cu-cylinder with 12.7 mm Ø
x = x =	25.4 g 12.7 s 25.4 s	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing

x = 25.4 wsoldered on a water cooled Cu-cylinder with 25.4 mm \emptyset x = FCmounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance and dispersion

